

# NZH series

## Single Zener diodes

Rev. 01 — 27 January 2010

Product data sheet

## 1. Product profile

### 1.1 General description

General-purpose Zener diodes in a SOD123F small and flat lead Surface-Mounted Device (SMD) plastic package.

### 1.2 Features

- Total power dissipation:  $\leq 500$  mW
- Wide working voltage range
- Small plastic package suitable for surface-mounted design
- Low differential resistance

### 1.3 Applications

- General regulation functions

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_F$	forward voltage	$I_F = 10$ mA	[1] -	-	0.9	V
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[2] -	-	500	mW
			[3] -	-	1	W

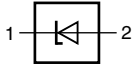

[1] Pulse test:  $t_p \leq 300$   $\mu$ s;  $\delta \leq 0.02$ .

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode <a href="#">[1]</a>		
2	anode		

[1] The marking bar indicates the cathode.

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NZH3V0B to NZH30C <a href="#">[1]</a>	-	plastic surface-mounted package; 2 leads	SOD123F

[1] The series consists of 25 types with nominal working voltages from 3.0 V to 30 V.

## 4. Marking

Table 4. Marking codes

Type number	Marking code	Type number	Marking code
NZH3V0B	CH	NZH10C	CW
NZH3V3A	CJ	NZH11C	CX
NZH3V6B	CK	NZH12B	CY
NZH3V9B	CL	NZH13B	D9
NZH4V3B	CM	NZH15B	D1
NZH4V7B	CN	NZH16C	D2
NZH5V1B	CP	NZH18C	D3
NZH5V6B	CQ	NZH20C	D4
NZH6V2B	CR	NZH22C	D5
NZH6V8B	CS	NZH24C	D6
NZH7V5C	CT	NZH27C	D7
NZH8V2B	CU	NZH30C	DA
NZH9V1B	CV	-	-

## 5. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
$I_F$	forward current		-	250	mA	
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[1]	-	500	mW
			[2]	-	1	W
$T_j$	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-55	+150	°C	
$T_{stg}$	storage temperature		-65	+150	°C	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[2] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	250	K/W
			[2]	-	-	125	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3]	-	-	70	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

[2] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

[3] Soldering point of cathode tab.

## 7. Characteristics

**Table 7. Characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$V_F$	forward voltage	$I_F = 10\text{ mA}$	[1]	-	-	0.9	V

[1] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$ .

**Table 8. Characteristics per type; NZH3V0B to NZH10C**

$T_j = 25\text{ °C}$  unless otherwise specified.

NZHxxx	Working voltage $V_Z$ (V); $I_Z = 20\text{ mA}$		Maximum differential resistance $r_{dif}$ ( $\Omega$ )		Reverse current $I_R$ ( $\mu\text{A}$ )		Diode capacitance $C_d$ (pF) <sup>[1]</sup>
	Min	Max	$I_Z = 1\text{ mA}$	$I_Z = 20\text{ mA}$	Max	$V_R$ (V)	Max
3V0B	2.85	3.15	1000	80	50	1	450
3V3A	3.16	3.38	1000	70	20	1	450
3V6B	3.42	3.78	1000	60	5	1	450
3V9B	3.71	4.10	1000	50	5	1	450

**Table 8. Characteristics per type; NZH3V0B to NZH10C ...continued**  
*T<sub>j</sub> = 25 °C unless otherwise specified.*

NZHxxx	Working voltage V <sub>Z</sub> (V); I <sub>Z</sub> = 20 mA		Maximum differential resistance r <sub>diff</sub> (Ω)		Reverse current I <sub>R</sub> (μA)		Diode capacitance C <sub>d</sub> (pF) <sup>[1]</sup>
	Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 20 mA	Max	V <sub>R</sub> (V)	Max
4V3B	4.17	4.43	1000	40	5	1	450
4V7B	4.55	4.80	900	25	5	1	300
5V1B	4.94	5.20	800	20	5	1.5	300
5V6B	5.45	5.73	500	13	5	2.5	300
6V2B	5.96	6.27	300	10	5	3	200
6V8B	6.49	6.83	150	8	2	3.5	200
7V5C	7.29	7.67	120	8	0.5	4	150
8V2B	8.02	8.36	120	8	0.5	5	150
9V1B	8.85	9.23	120	8	0.5	6	150
10C	9.70	10.20	120	8	0.2	7	90

[1] f = 1 MHz; V<sub>R</sub> = 0 V

**Table 9. Characteristics per type; NZH11C to NZH20C**  
*T<sub>j</sub> = 25 °C unless otherwise specified.*

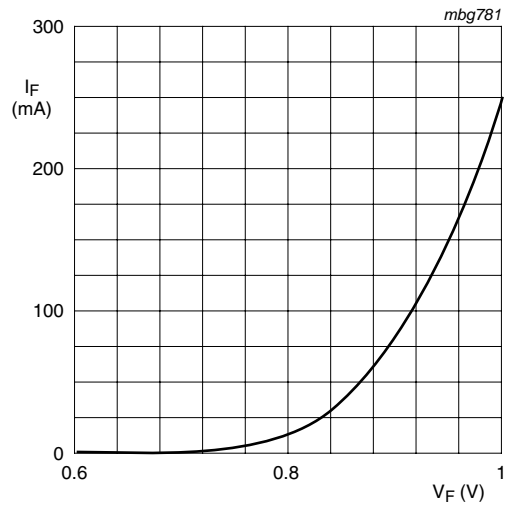
NZHxxx	Working voltage V <sub>Z</sub> (V); I <sub>Z</sub> = 10 mA		Maximum differential resistance r <sub>diff</sub> (Ω)		Reverse current I <sub>R</sub> (μA)		Diode capacitance C <sub>d</sub> (pF) <sup>[1]</sup>
	Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 10 mA	Max	V <sub>R</sub> (V)	Max
11C	10.82	11.38	120	10	0.04	8	85
12B	11.44	12.03	110	12	0.04	9	85
13B	12.35	13.65	110	14	0.04	10	80
15B	14.25	15.75	110	16	0.04	11	75
16C	15.69	16.51	150	18	0.04	12	75
18C	17.42	18.33	150	23	0.04	13	70
20C	19.23	20.22	200	28	0.04	15	60

[1] f = 1 MHz; V<sub>R</sub> = 0 V

**Table 10. Characteristics per type; NZH22C to NZH30C**  
*T<sub>j</sub> = 25 °C unless otherwise specified.*

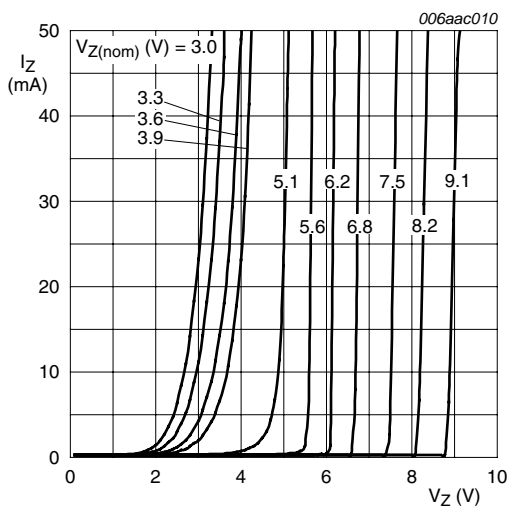
NZHxxx	Working voltage V <sub>Z</sub> (V); I <sub>Z</sub> = 5 mA		Maximum differential resistance r <sub>diff</sub> (Ω)		Reverse current I <sub>R</sub> (μA)		Diode capacitance C <sub>d</sub> (pF) <sup>[1]</sup>
	Min	Max	I <sub>Z</sub> = 1 mA	I <sub>Z</sub> = 5 mA	Max	V <sub>R</sub> (V)	Max
22C	21.08	22.17	200	30	0.04	17	60
24C	23.12	24.31	200	35	0.04	19	55
27C	25.63	26.95	250	45	0.04	21	50
30C	28.50	31.50	250	55	0.04	23	50

[1] f = 1 MHz; V<sub>R</sub> = 0 V



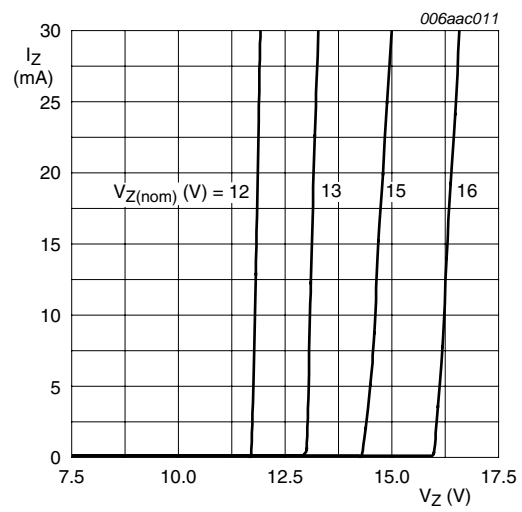
$T_j = 25\text{ }^\circ\text{C}$

**Fig 1. Forward current as a function of forward voltage; typical values**



$T_j = 25\text{ }^\circ\text{C}$

**Fig 2. Working current as a function of working voltage; typical values**



$T_j = 25\text{ }^\circ\text{C}$

**Fig 3. Working current as a function of working voltage; typical values**

8. Package outline

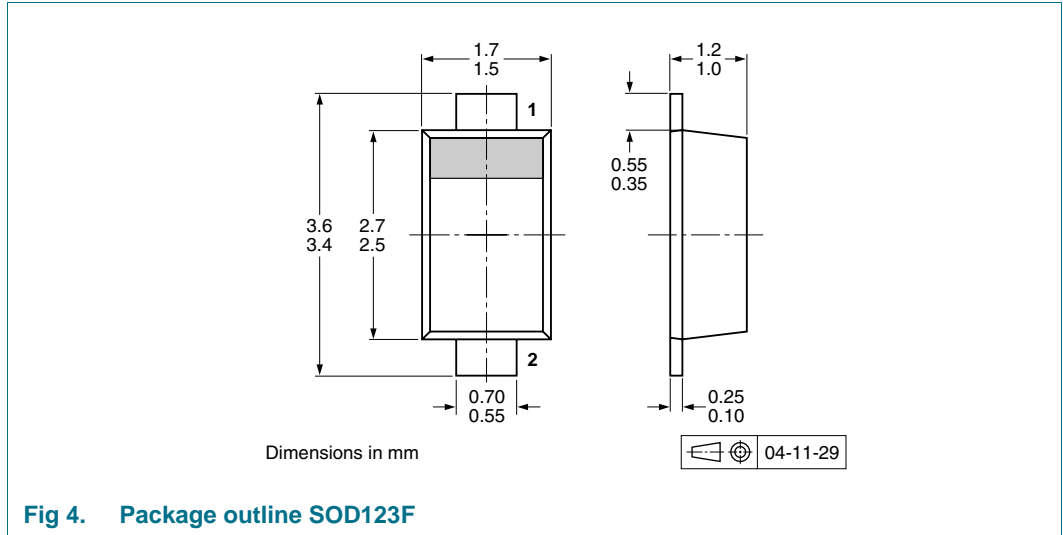


Fig 4. Package outline SOD123F

9. Packing information

Table 11. Packing methods

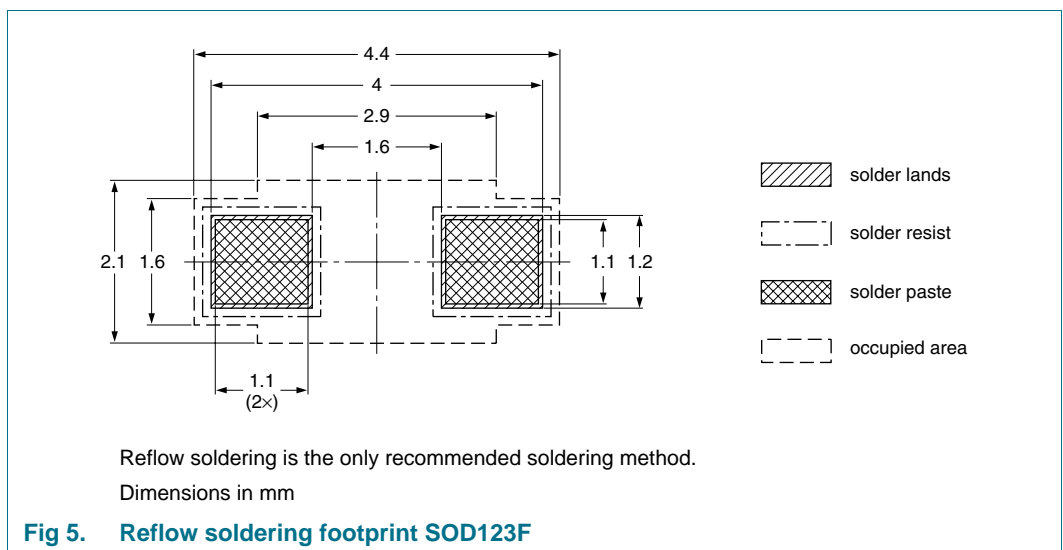
The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

Type number	Package	Description	Packing quantity	
			3000	10000
NZH3V0B to NZH30C <sup>[2]</sup>	SOD123F	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see [Section 13](#).

[2] The series consists of 25 types with nominal working voltages from 3.0 V to 30 V.

10. Soldering



## 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NZH_SER_1	20100127	Product data sheet	-	-

## 12. Legal information

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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